



Specifically designed for small-signal  
medium power audio-amplifiers



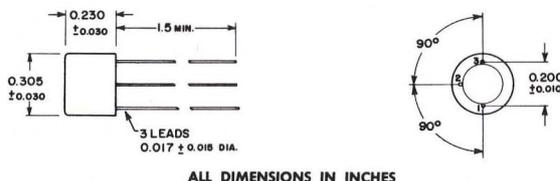
**qualification testing**

To ensure maximum reliability, stability, and long life, all units are heat cycled from  $-55^{\circ}\text{C}$  and room humidity to  $+85^{\circ}\text{C}$  and 95% relative humidity for four complete cycles over an eight hour period. All transistors are thoroughly tested for rigid adherence to specified design characteristics on CAT (Central Automatic Testing) equipment.

**mechanical data**

Metal case with new glass-to-metal hermetic seal between case and leads eliminates all welding and soldering operations from the sealing process. Standard JEDEC E3-51 base, TO-9 package. Approximate unit weight 1 gram.

ALL LEADS INSULATED FROM CASE



**maximum ratings at 25°C ambient temperature (unless otherwise noted)**

	2N1382	2N1383
Collector - Base Voltage . . . . .	-25v	-25v
Emitter - Base Voltage . . . . .	-15v	-15v
Collector - Emitter Voltage . . . . .	-25v	-25v
Collector Current . . . . .	-200ma	-200ma
Total Device Dissipation . . . . .	200mw	200mw
Collector Junction Temperature . . . . .	85°C	85°C
Storage Temperature Range . . . . .	-55°C to +85°C	

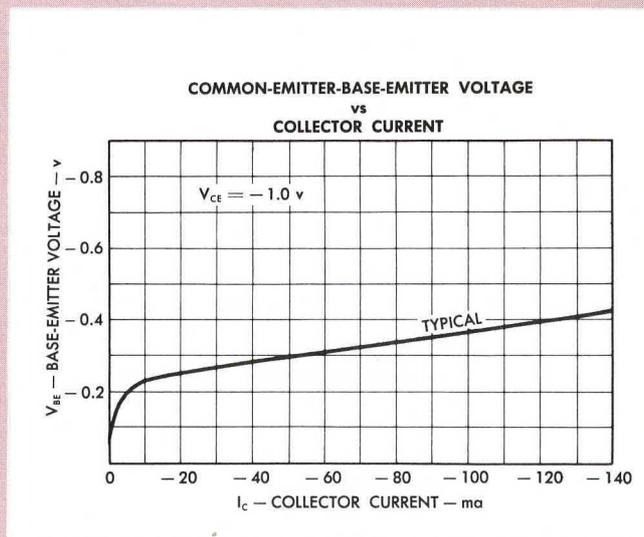
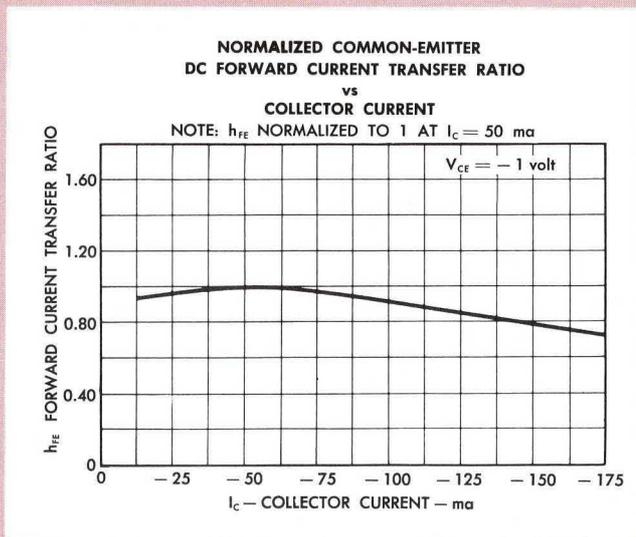
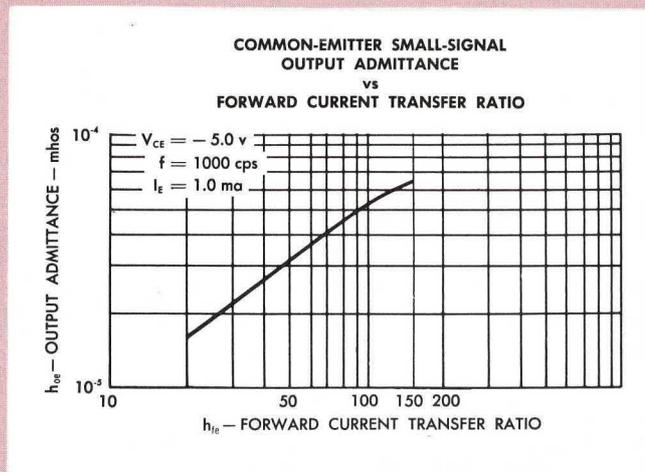
**electrical characteristics at 25°C ambient temperature**

PARAMETER	TEST CONDITIONS	2N1382			2N1383			UNIT
		min.	typ.	max.	min.	typ.	max.	
$I_{CBO}$ Collector Reverse Current	$V_{CB} = -20v, I_E = 0$			-14			-14	$\mu a$
$I_{EBO}$ Emitter Reverse Current	$V_{EB} = -1.5v, I_C = 0$		-3			-3		$\mu a$
$h_{FE}$ dc Forward Current Transfer Ratio*	$V_{CE} = -1v, I_C = -50 ma$	50	80	150	30	50	150	—
$f_{\alpha B}$ Alpha-Cutoff Frequency	$V_{CB} = -5v, I_C = -1 ma$		2			1.5		mc
$h_{fe}$ ac Common-Emitter Forward Current Transfer Ratio	$f = 1000 cps, V_{CE} = -5v, I_E = 1 ma$		80			50		—
$h_{ib}$ Common-Base Input Impedance	$f = 1000 cps, V_{BE} = -5v, I_E = 1 ma$		30			30		ohm
$h_{ob}$ Common-Base Output Admittance	$f = 1000 cps, V_{BE} = -5v, I_E = 1 ma$		0.5			0.6		$\mu mho$
$h_{rb}$ Common-Base Reverse Voltage Transfer Ratio	$f = 1000 cps, V_{BE} = -5v, I_E = 1 ma$		5			4		$X10^{-4}$
Noise Figure 1000 cps†			6.5			7.0		db

\*Tolerance on all values  $\pm 10\%$  for test set correlation.  
†Conventional noise compared to 1000 cps and 1 cycle bandwidth.

# TYPES 2N1382, 2N1383

## TYPICAL CHARACTERISTICS



**TEXAS INSTRUMENTS**

INCORPORATED

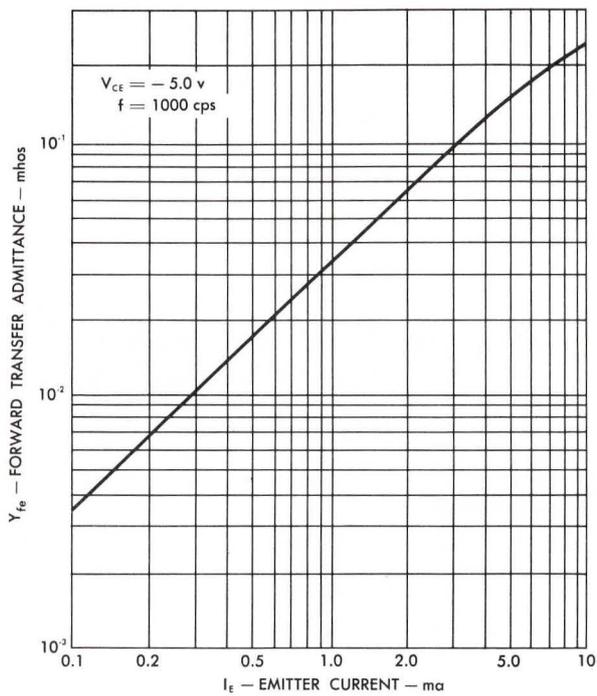
SEMICONDUCTOR COMPONENTS DIVISION

P. O. BOX 312 • 13500 N. CENTRAL EXPRESSWAY  
DALLAS, TEXAS

# TYPES 2N1382, 2N1383

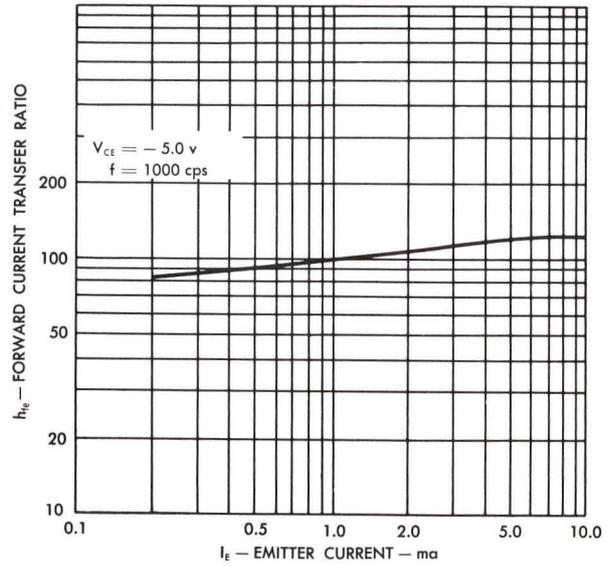
## TYPICAL CHARACTERISTICS

COMMON-EMITTER SMALL-SIGNAL  
FORWARD TRANSFER ADMITTANCE  
vs  
EMITTER CURRENT

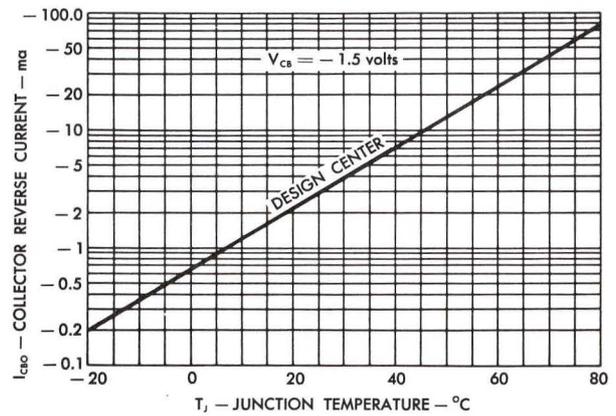


NORMALIZED COMMON-EMITTER SMALL-SIGNAL  
FORWARD CURRENT TRANSFER RATIO

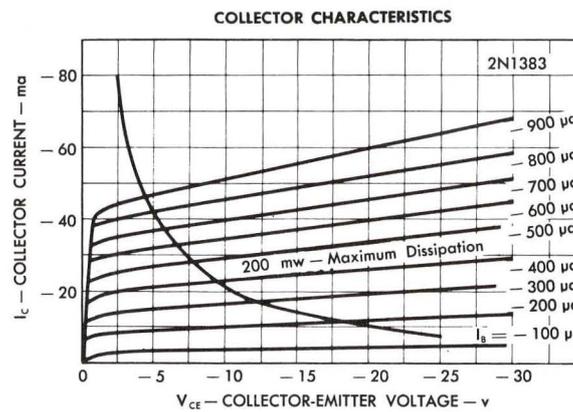
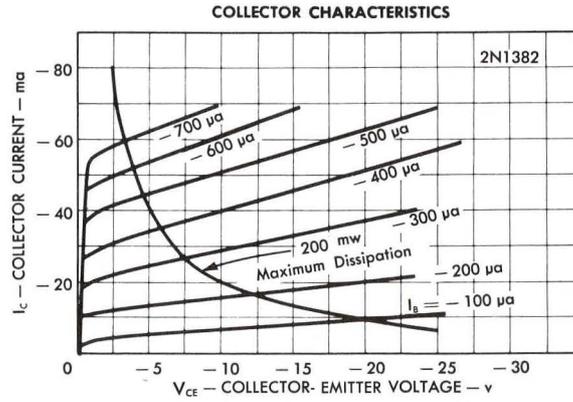
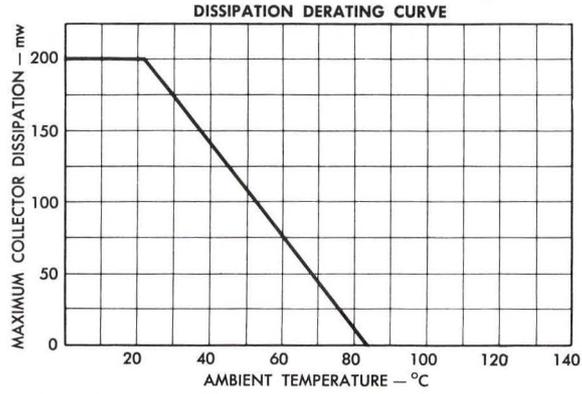
vs  
EMITTER CURRENT  
NOTE: NORMALIZED TO 100 AT  $I_E = 1$  ma



COLLECTOR REVERSE CURRENT vs.  
JUNCTION TEMPERATURE



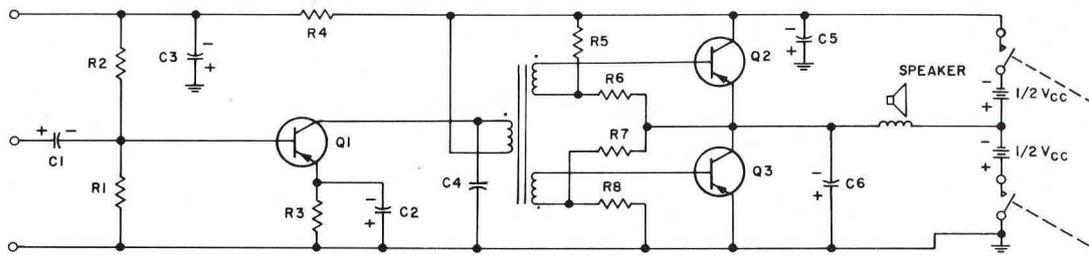
SEMICONDUCTOR-COMPONENTS DIVISION



# TYPES 2N1382, 2N1383

## TYPICAL AMPLIFIER CIRCUITS

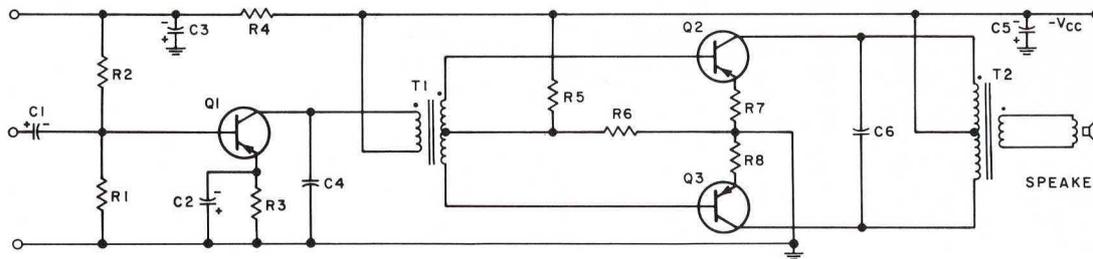
### PUSH-PUSH AMPLIFIER



PARTS LIST 12V PUSH-PUSH AMPLIFIER

$V_{cc} = 12\text{ v}$	$C_1 = 5\ \mu\text{f}/3\text{v}$
$R_1 = 3.3\ \text{K}$	$C_2 = 150\ \mu\text{f}/3\text{v}$
$R_2 = 39\ \text{K}$	$C_3 = 50\ \mu\text{f}/12\text{v}$
$R_3 = 470\ \text{ohm}$	$C_4 = 0.0022\ \mu\text{f}$
$R_4 = 330\ \text{ohms}$	$C_5 = 50\ \mu\text{f}/12\text{v}$
$R_5 = 2.7\ \text{K}$	$C_6 = 1\ \mu\text{f}/12\text{v}$
$R_6 = 680\ \text{ohms}$	Speaker 25 ohms
$R_7 = 2.7\ \text{K}$	$Q_1, Q_2, Q_3$ 2N1383 per table
$R_8 = 68\ \text{ohms}$	$T_1$ 6.5 K to 600 ohms split

### PUSH-PULL AMPLIFIER



PARTS LIST 12V PUSH-PULL AMPLIFIER

$V_{cc} = 12\ \text{v}$	$C_1 = 5\ \mu\text{f}/3\text{v}$
$R_1 = 4.7\ \text{K}$	$C_2 = 100\ \mu\text{f}/$
$R_2 = 27\ \text{K}$	$C_3 = 50\ \mu\text{f}/12\text{v}$
$R_3 = 1\ \text{K}$	$C_4 = 0.001\ \mu\text{f}$
$R_4 = 330\ \text{ohms}$	$C_5 = 50\ \mu\text{f}/12\text{v}$
$R_5 = 3.9\ \text{K}$	$C_6 = 0.068\ \mu\text{f}$
$R_6 = 47\ \text{ohms}$	Speaker 3.2 ohms
$R_7 = 4.7\ \text{ohms}$	$Q_1, Q_2, Q_3$ 2N1383 per table
$R_8 = 4.7\ \text{ohms}$	$T_1$ 7.5 K to 1.48 K center tapped
	$T_2$ 288 ohms C.T. to 3.2 ohms

### AMPLIFIER PERFORMANCE DATA

	Push-Push	Pull-Pull
Supply Voltage	12 v	12 v
Rated Power Out	500 mw	500 mw
Power at 10% Distortion	620 mw	620 mw
Distortion at Rated Power	6%	7%
Distortion at 100 mw Power	3%	3%
Input Impedance	1.0 K	1 K
Input Voltage for 100 mw Power Out	4 mv	5 mv
Power Gain	67 db	65 db
Response Down 3 db at	120 cps	120 cps
Battery Drain Zero Out	5.0 kc	5 kc
Rated Out	9.0 ma	8 ma
	57 ma	69 ma

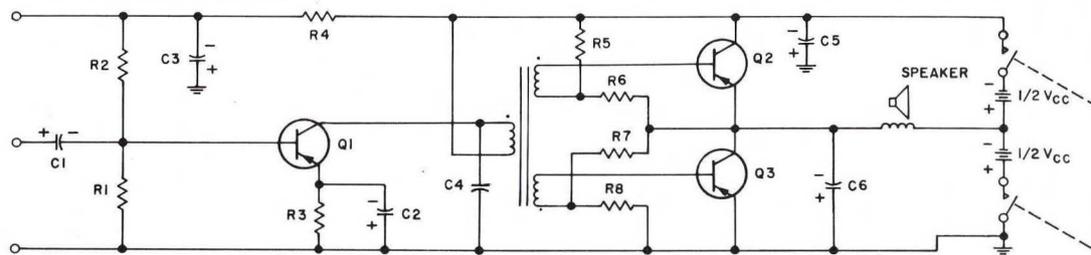


SEMICONDUCTOR-COMPONENTS DIVISION

# TYPES 2N1382, 2N1383

## TYPICAL AMPLIFIER CIRCUITS

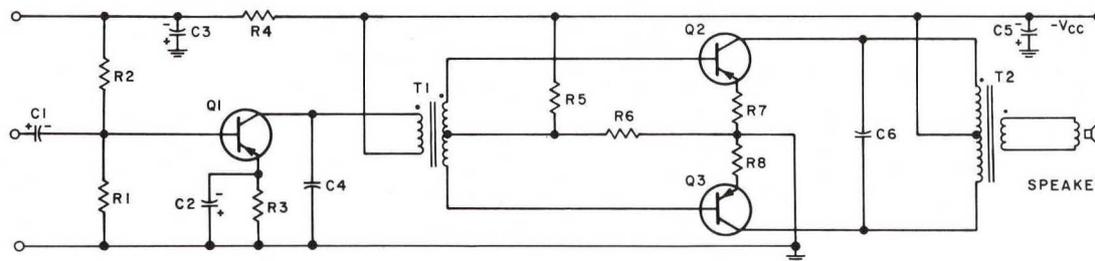
### PUSH-PUSH AMPLIFIER



#### PARTS LIST 12V PUSH-PUSH AMPLIFIER

$V_{cc} = 12\text{ v}$	$C_1 = 5\ \mu\text{f}/3\text{v}$
$R_1 = 3.3\ \text{K}$	$C_2 = 150\ \mu\text{f}/3\text{v}$
$R_2 = 39\ \text{K}$	$C_3 = 50\ \mu\text{f}/12\text{v}$
$R_3 = 470\ \text{ohm}$	$C_4 = 0.0022\ \mu\text{f}$
$R_4 = 330\ \text{ohms}$	$C_5 = 50\ \mu\text{f}/12\text{v}$
$R_5 = 2.7\ \text{K}$	$C_6 = 1\ \mu\text{f}/12\text{v}$
$R_6 = 680\ \text{ohms}$	Speaker 25 ohms
$R_7 = 2.7\ \text{K}$	$Q_1, Q_2, Q_3$ 2N1383 per table
$R_8 = 68\ \text{ohms}$	$T_1$ 6.5 K to 600 ohms split

### PUSH-PULL AMPLIFIER



#### PARTS LIST 12V PUSH-PULL AMPLIFIER

$V_{cc} = 12\ \text{v}$	$C_1 = 5\ \mu\text{f}/3\text{v}$
$R_1 = 4.7\ \text{K}$	$C_2 = 100\ \mu\text{f}/$
$R_2 = 27\ \text{K}$	$C_3 = 50\ \mu\text{f}/12\text{v}$
$R_3 = 1\ \text{K}$	$C_4 = 0.001\ \mu\text{f}$
$R_4 = 330\ \text{ohms}$	$C_5 = 50\ \mu\text{f}/12\text{v}$
$R_5 = 3.9\ \text{K}$	$C_6 = 0.068\ \mu\text{f}$
$R_6 = 47\ \text{ohms}$	Speaker 3.2 ohms
$R_7 = 4.7\ \text{ohms}$	$Q_1, Q_2, Q_3$ 2N1383 per table
$R_8 = 4.7\ \text{ohms}$	$T_1$ 7.5 K to 1.48 K center tapped
	$T_2$ 288 ohms C.T. to 3.2 ohms

#### AMPLIFIER PERFORMANCE DATA

	Push-Push	Pull-Pull
Supply Voltage	12 v	12 v
Rated Power Out	500 mw	500 mw
Power at 10% Distortion	620 mw	620 mw
Distortion at Rated Power	6%	7%
Distortion at 100 mw Power	3%	3%
Input Impedance	1.0 K	1 K
Input Voltage for 100 mw		
Power Out	4 mv	5 mv
Power Gain	67 db	65 db
Response Down	120 cps	120 cps
3 db at	5.0 kc	5 kc
Battery Drain Zero Out	9.0 ma	8 ma
Rated Out	57 ma	69 ma



# TYPES 2N1382, 2N1383

## APPLICATION NOTES

### Color Dots and Beta Brackets

The transistors are color coded to identify matched pairs for push-pull audio applications. The dc Beta spread is divided into 7 equal brackets such that the maximum current gain variation per bracket is 2 db. Any two units within a bracket constitute a matched pair. The 7 brackets, beta range, and corresponding color codes are indicated below:

Bracket No.	Beta Range*	Color Code
1	30-38	Brown
2	38-50	Red
3	50-60	Orange
4	60-75	Yellow
5	75-95	Green
6	95-120	Blue
7	120-150	Violet

The above bracketing can be utilized to minimize the gain variation in driver-output combinations. The group combinations shown below will match high and low gain units by color code for outstanding uniformity in production amplifiers.

	Combination			
	A	B	C	D
Driver Bracket	4	5	6	7
Output Bracket	4	3	2	1

For additional information regarding the use of this system in audio amplifiers, contact your nearest Texas Instruments field sales office.

\*Tolerance on all values  $\pm 10\%$  for test set correlation.